

Micro MINI E0C6011

4-bit Single Chip Microcomputer



- E0C6200B Core CPU
- Low Voltage and Low Power
- Built-in LCD Driver
- Low Cost Performance

■ DESCRIPTION

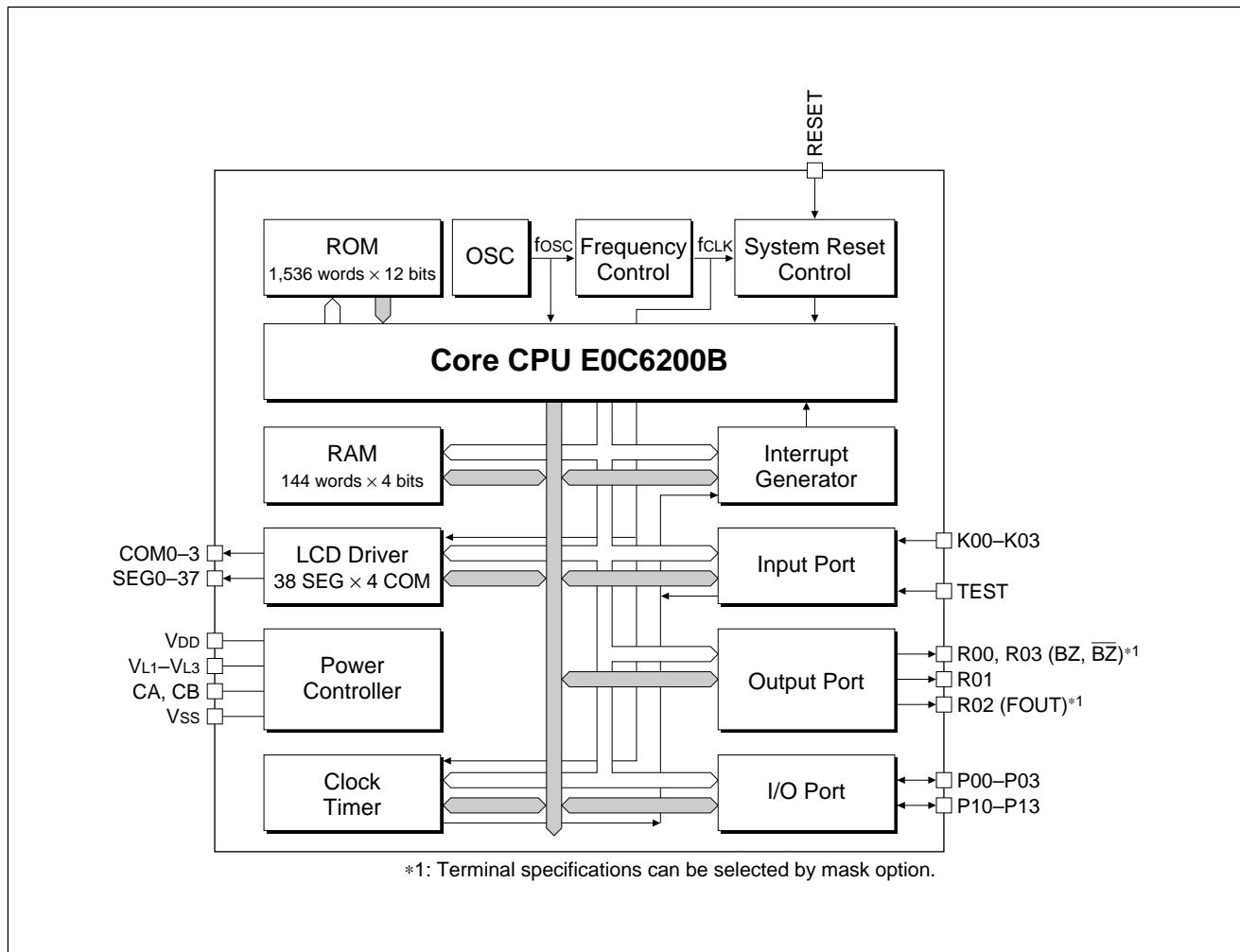
Micro MINI "E0C6011" is a single chip microcomputer for battery-driven products with 7-segment LCD display. It achieves low cost performance, and is suitable for a product added some feature instead of standard IC. It consists that Seiko Epson's original core CPU E0C6200B, LCD driver (38 segments × 4 commons), 144 words RAM, 1.5K words ROM, clock timer and so on.

■ FEATURES

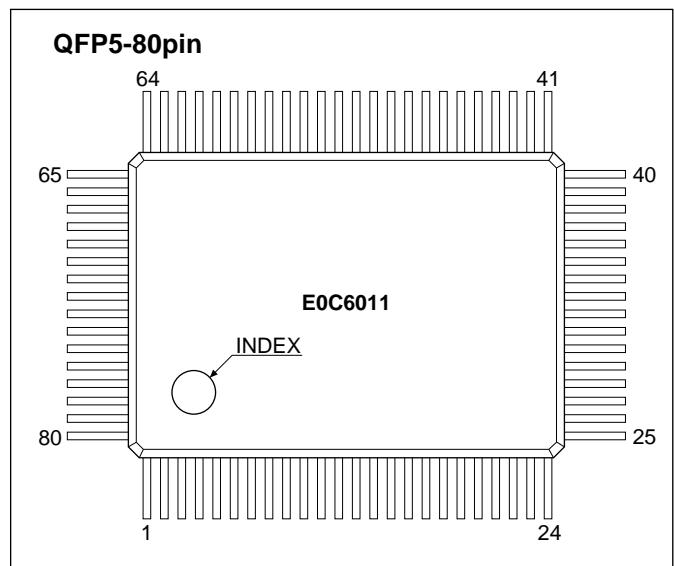
- CMOS LSI 4-bit parallel processing
- Clock 65 to 260kHz (CR oscillation)
- Instruction set 101 instructions (supports SLEEP mode)
- ROM capacity 1,536 × 12 bits
- RAM capacity 144 × 4 bits
- I/O port
 - I: 4 bits (with pull-down resistor selectable by mask option)
 - O: 4 bits (clock and buzzer outputs possible by mask option)
 - I/O: 8 bits
- Supply voltage detector (SVD) No support
- Clock timer 1ch.
- LCD driver 38 segments × 4/3/2 commons
- Interrupt
 - External : Key interrupt 1 line
 - Internal : Timer interrupt 1 line
- Operation voltage 1.2 to 1.8V
- Power consumption
 - 0.3µA (SLEEP)
 - 4µA (65kHz, 1.5V, HALT)
 - 8µA (65kHz, 1.5V, RUN)
 - 26µA (260kHz, 1.5V, RUN)
- Package Die form (pad pitch = 130µm) or QFP5-80pin/QFP14-80pin

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■ BLOCK DIAGRAM



■ PIN CONFIGURATION



No.	Pin name	No.	Pin name	No.	Pin name	No.	Pin name
1	SEG35	21	R03	41	N.C.	61	N.C.
2	N.C.	22	N.C.	42	N.C.	62	N.C.
3	N.C.	23	N.C.	43	SEG1	63	N.C.
4	SEG36	24	N.C.	44	SEG2	64	SEG19
5	SEG37	25	Vss	45	SEG3	65	TEST
6	K03	26	RESET	46	SEG4	66	SEG20
7	K02	27	N.C.	47	SEG5	67	SEG21
8	K01	28	N.C.	48	SEG6	68	SEG22
9	K00	29	N.C.	49	SEG7	69	SEG23
10	P13	30	V _{DD}	50	SEG8	70	SEG24
11	P12	31	V _{L3}	51	SEG9	71	SEG25
12	P11	32	V _{L2}	52	SEG10	72	SEG26
13	P10	33	V _{L1}	53	SEG11	73	SEG27
14	P03	34	CB	54	SEG12	74	SEG28
15	P02	35	CA	55	SEG13	75	SEG29
16	P01	36	COM3	56	SEG14	76	SEG30
17	P00	37	COM2	57	SEG15	77	SEG31
18	R02	38	COM1	58	SEG16	78	SEG32
19	R01	39	COM0	59	SEG17	79	SEG33
20	R00	40	SEG0	60	SEG18	80	SEG34

N.C. = No Connection

QFP14-80pin		No.	Pin name						
1	N.C.	21	SEG36	41	N.C.	61	N.C.		
2	N.C.	22	N.C.	42	N.C.	62	SEG1		
3	SEG19	23	N.C.	43	Vss	63	SEG2		
4	TEST	24	SEG37	44	RESET	64	SEG3		
5	SEG20	25	K03	45	N.C.	65	SEG4		
6	SEG21	26	K02	46	OSC2	66	SEG5		
7	SEG22	27	K01	47	OSC1	67	SEG6		
8	SEG23	28	K00	48	VDD	68	SEG7		
9	SEG24	29	P13	49	VL3	69	SEG8		
10	SEG25	30	P12	50	VL2	70	SEG9		
11	SEG26	31	P11	51	VL1	71	SEG10		
12	SEG27	32	P10	52	CB	72	SEG11		
13	SEG28	33	P03	53	CA	73	SEG12		
14	SEG29	34	P02	54	COM3	74	SEG13		
15	SEG30	35	P01	55	COM2	75	SEG14		
16	SEG31	36	P00	56	COM1	76	SEG15		
17	SEG32	37	R02	57	COM0	77	SEG16		
18	SEG33	38	R01	58	SEG0	78	SEG17		
19	SEG34	39	R00	59	N.C.	79	SEG18		
20	SEG35	40	R03	60	N.C.	80	N.C.		

N.C. = No Connection

■ PIN DESCRIPTION

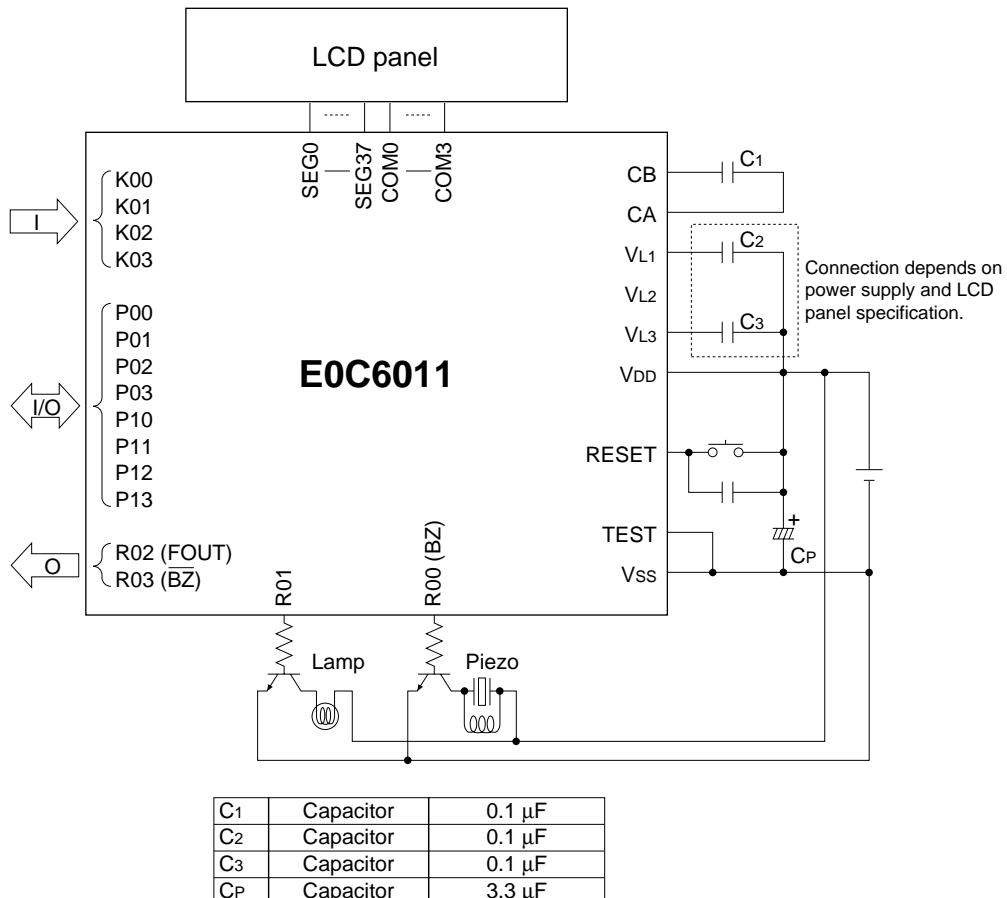
Pin name	Pin No.		I/O	Function
	QFP14	QFP5		
VDD	48	30	(I)	Power supply terminal (+)
Vss	43	25	(I)	Power supply terminal (-)
VL1-3	51-49	33-31	-	Power source for LCD
CA, CB	53, 52	35, 34	-	Booster capacitor connecting terminal
K00-03	28-25	9-6	I	Input port terminal
P00-03	36-33	17-14	I/O	I/O port terminal
P10-13	32-29	13-10	I/O	I/O port terminal
R00	39	20	O	Output port terminal (BZ output is selectable *)
R03	40	21	O	Output port terminal (B \bar{Z} output is selectable *)
R01	38	19	O	Output port terminal
R02	37	18	O	Output port terminal (FOUT output is selectable *)
SEG0-37	58, 62-79, 3-21, 24	40, 43-60, 64, 66-80, 1, 4, 5	O	LCD segment output (DC output is selectable *)
COM0-3	57-54	39-36	O	LCD common output terminal (1/4, 1/3 or 1/2 duty are selectable *)
RESET	44	26	I	Initial reset input terminal
TEST	4	65	I	Test input terminal

* Can be selected by mask option

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■ BASIC EXTERNAL CONNECTION DIAGRAM

Piezo Buzzer Single Terminal Driving



■ ELECTRICAL CHARACTERISTICS

● Absolute Maximum Ratings

Rating	Symbol	Value	Unit
Supply voltage	Vss	-5.0 to 0.5	V
Input voltage (1)	V _i	Vss - 0.3 to 0.5	V
Input voltage (2)	V _{iosc}	Vss - 0.3 to 0.5	V
Operating temperature	T _{opr}	-20 to 70	°C
Storage temperature	T _{stg}	-65 to 150	°C
Soldering temperature / time	T _{sol}	260°C, 10sec (lead section)	—

● Recommended Operating Conditions

(Ta=-20 to 70°C)

Condition	Symbol	Remark	Min.	Typ.	Max.	Unit
Supply voltage	Vss	V _{DD} =0V	-1.8	-1.5	-1.2	V
Oscillation frequency	f _{osc}	CR oscillation		65		kHz
		CR oscillation		130		kHz
		CR oscillation		195		kHz
		CR oscillation		260		kHz
Booster capacitor	C ₁		0.1			µF

● DC Characteristics

(Unless otherwise specified: VDD=0V, VSS=-1.5V, fCLK=65kHz, Ta=25°C, VL1–VL3 are internal voltage, C1–C3=0.1μF)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
High level input voltage (1)	VIH1	K00–03, P00–03, P10–13	0.2·VSS		0	V
High level input voltage (2)	VIH2	RESET, TEST	0.1·VSS		0	V
Low level input voltage (1)	VIL1	K00–03, P00–03, P10–13	VSS		0.8·VSS	V
Low level input voltage (2)	VIL2	RESET, TEST	VSS		0.9·VSS	V
High level input current (1)	IiH1	VIH1=0V, No pull-down	K00–03, P00–03, P10–13	0		0.5 μA
High level input current (2)	IiH2	VIH2=0V, Pull-down	K00–03	5		20 μA
High level input current (3)	IiH3	VIH3=0V, Pull-down	P00–03, P10–13 RESET, TEST	25		100 μA
Low level input current	IiL	VIL=VSS	K00–03, P00–03, P10–13 RESET, TEST	-0.5		0 μA
High level output current (1)	IOH1	VOH1=0.1·VSS	R00, R03			-300 μA
High level output current (2)	IOH2	VOH2=0.1·VSS	R01, R02, P00–03, P10–13			-150 μA
Low level output current (1)	IOL1	VOL1=0.9·VSS	R00, R03	1400		μA
Low level output current (2)	IOL2	VOL2=0.9·VSS	R01, R02, P00–03, P10–13	700		μA
Common output current	IOH3	VOH3=-0.05V	COM0–3			-3 μA
	IOL3	VOL3=VL3+0.05V		3		μA
Segment output current (during LCD output)	IOH4	VOH4=-0.05V	SEG0–37			-3 μA
	IOL4	VOL4=VL3+0.05V		3		μA
Segment output current (during DC output)	IOH5	VOH5=0.1·VSS	SEG0–37			-100 μA
	IOL5	VOL5=0.9·VSS		100		μA

● Analog Circuit Characteristics and Current Consumption

LCD Drive Voltage

• 4.5 V LCD panel, 1/4, 1/3, 1/2 duty, 1/3 bias (VL2 is shorted to Vss inside the IC)

(Unless otherwise specified: VDD=0V, VSS=-1.5V, fCLK=65kHz, Ta=25°C, VL1–VL3 are internal voltage, C1–C3=0.1μF, Internal CR oscillation circuit)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
LCD drive voltage	VL1	Connect 1 MΩ load resistor between VDD and VL1 (without panel load)		VSS		V
	VL2	Connect 1 MΩ load resistor between VDD and VL2 (without panel load)	2·VL1 - 0.1		2·VL1 ×0.9	V
	VL3	Connect 1 MΩ load resistor between VDD and VL3 (without panel load)	3·VL1 - 0.1		3·VL1 ×0.9	V

• 3 V LCD panel, 1/4, 1/3, 1/2 duty, 1/2 bias (VL3 is shorted to Vss inside the IC and VL1 is shorted to VL2 outside the IC)

(Unless otherwise specified: VDD=0V, VSS=-1.5V, fCLK=65kHz, Ta=25°C, VL1–VL3 are internal voltage, C1–C3=0.1μF, Internal CR oscillation circuit)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
LCD drive voltage	VL1	Connect 1 MΩ load resistor between VDD and VL1 (without panel load)		VSS		V
	VL2	Connect 1 MΩ load resistor between VDD and VL2 (without panel load)		VSS		V
	VL3	Connect 1 MΩ load resistor between VDD and VL3 (without panel load)	2·VL1 - 0.1		2·VL1 ×0.9	V

Current Consumption

(Unless otherwise specified: VDD=0V, VSS=-1.5V, Ta=25°C, VL1–VL3 are internal voltage, C1–C3=0.1μF, RCR is internal resistor, fCLK=65kHz)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Current consumption (fosc=65kHz)	IOP1	During HALT	Without panel load	4	6	μA
		During execution		8	11	μA
Current consumption (fosc=130kHz)	IOP2	During HALT	Without panel load	8	11	μA
		During execution		15	21	μA
Current consumption (fosc=195kHz)	IOP3	During HALT	Without panel load	11	15	μA
		During execution		20	26	μA
Current consumption (fosc=260kHz)	IOP4	During HALT	Without panel load	14	19	μA
		During execution		26	34	μA
Current consumption	IOP5	During SLEEP	Without panel load		0.3	μA

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● Oscillation Characteristics

Oscillation characteristics will vary according to different conditions (elements used, board pattern). Use the following characteristics are as reference values.

(Unless otherwise specified: VDD=0V, VSS=-1.5V, TA=25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation frequency dispersion	fosc1	VSS=-1.5V	42.3	65	87.8	kHz
Oscillation start time	tsta	VSS=-1.5V			3	mS
Frequency v.s. voltage deviation	df1/dv	VSS=-1.2 to -1.8V	-30		30	%
Frequency v.s. temperature deviation	df1/dta	VSS=-1.5V, TA=-25 to 75°C	-15		15	%

(Unless otherwise specified: VDD=0V, VSS=-1.5V, TA=25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation frequency dispersion	fosc2	VSS=-1.5V	84.5	130	175.5	kHz
Oscillation start time	tsta	VSS=-1.5V			3	mS
Frequency v.s. voltage deviation	df2/dv	VSS=-1.2 to -1.8V	-30		30	%
Frequency v.s. temperature deviation	df2/dta	VSS=-1.5V, TA=-25 to 75°C	-15		15	%

(Unless otherwise specified: VDD=0V, VSS=-1.5V, TA=25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation frequency dispersion	fosc3	VSS=-1.5V	136.5	195	253.5	kHz
Oscillation start time	tsta	VSS=-1.5V			3	mS
Frequency v.s. voltage deviation	df3/dv	VSS=-1.2 to -1.8V	-30		30	%
Frequency v.s. temperature deviation	df3/dta	VSS=-1.5V, TA=-25 to 75°C	-15		15	%

(Unless otherwise specified: VDD=0V, VSS=-1.5V, TA=25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation frequency dispersion	fosc4	VSS=-1.5V	182	260	338	kHz
Oscillation start time	tsta	VSS=-1.5V			3	mS
Frequency v.s. voltage deviation	df4/dv	VSS=-1.2 to -1.8V	-30		30	%
Frequency v.s. temperature deviation	df4/dta	VSS=-1.5V, TA=-25 to 75°C	-15		15	%

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